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SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

2SK2197
(FP20W50VX2)

500V 20A

FEATURES

- Input capacitance (Ciss) is small. Especially, input capacitance at 0 biass is small.
- The static Rds(on) is small.
- The switching time is fast.

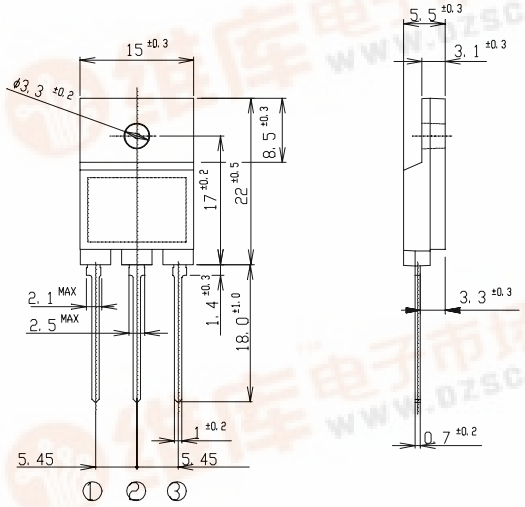
APPLICATION

- Switching power supply of AC 100V input
- High voltage power supply
- Inverter

OUTLINE DIMENSIONS

Case : ITO-3P

(Unit : mm)



①: G
②: D
③: S

RATINGS

●Absolute Maximum Ratings （Tc = 25℃）

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		−55～150	℃
Channel Temperature	T_{ch}		150	
Drain-Source Voltage	V_{DSS}		500	V
Gate-Source Voltage	V_{GSS}		±30	
Continuous Drain Current (DC)	I_D		20	A
Continuous Drain Current (Peak)	I_{DP}		60	
Continuous Source Current (DC)	I_S		20	
Total Power Dissipation	P_T		70	W
Single Pulse Avalanche Current	I_{AS}	T_{ch} = 25℃	20	A
Dielectric Strength	V_{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

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●Electrical Characteristics Tc = 25℃

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	I_D = 1mA, V_{GS} = 0V	500			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 500V, V_{GS} = 0V			250	μA
Gate-Source Leakage Current	I_{GSS}	V_{GS} = ±30V, V_{DS} = 0V			±0.1	
Forward Transconductance	g_{fs}	I_D = 10A, V_{DS} = 10V	6	15		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	I_D = 10A, V_{GS} = 10V		0.27	0.35	Ω
Gate Threshold Voltage	V_{TH}	I_D = 1mA, V_{DS} = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forwade Voltage	V_{SD}	I_S = 10A, V_{GS} = 0V			1.5	
Thermal Resistance	θ jc	junction to case			1.78	℃/W
Total Gate Charge	Q_g	V_{DD} = 400V, V_{GS} = 10V, I_D = 20A		85		nC
Input Capacitance	C_{iss}	V_{DS} = 10V, V_{GS} = 0V, f = 1MHz		2400		pF
Reverse Transfer Capacitance	C_{rss}			170		
Output Capacitance	C_{oss}			500		
Turn-On Time	t_{on}	I_D = 10A, V_{GS} = 10V, R_L = 15Ω		135	225	ns
Turn-Off Time	t_{off}			340	565	

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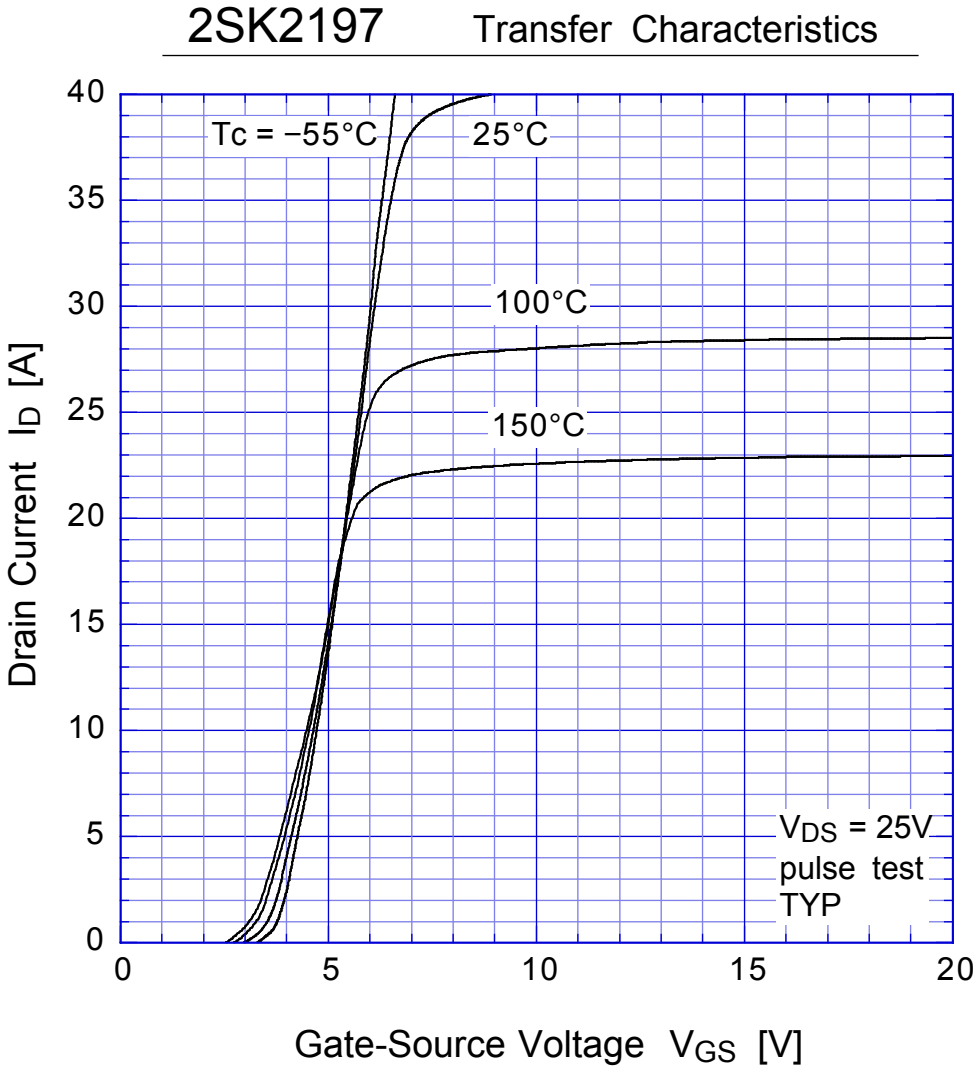
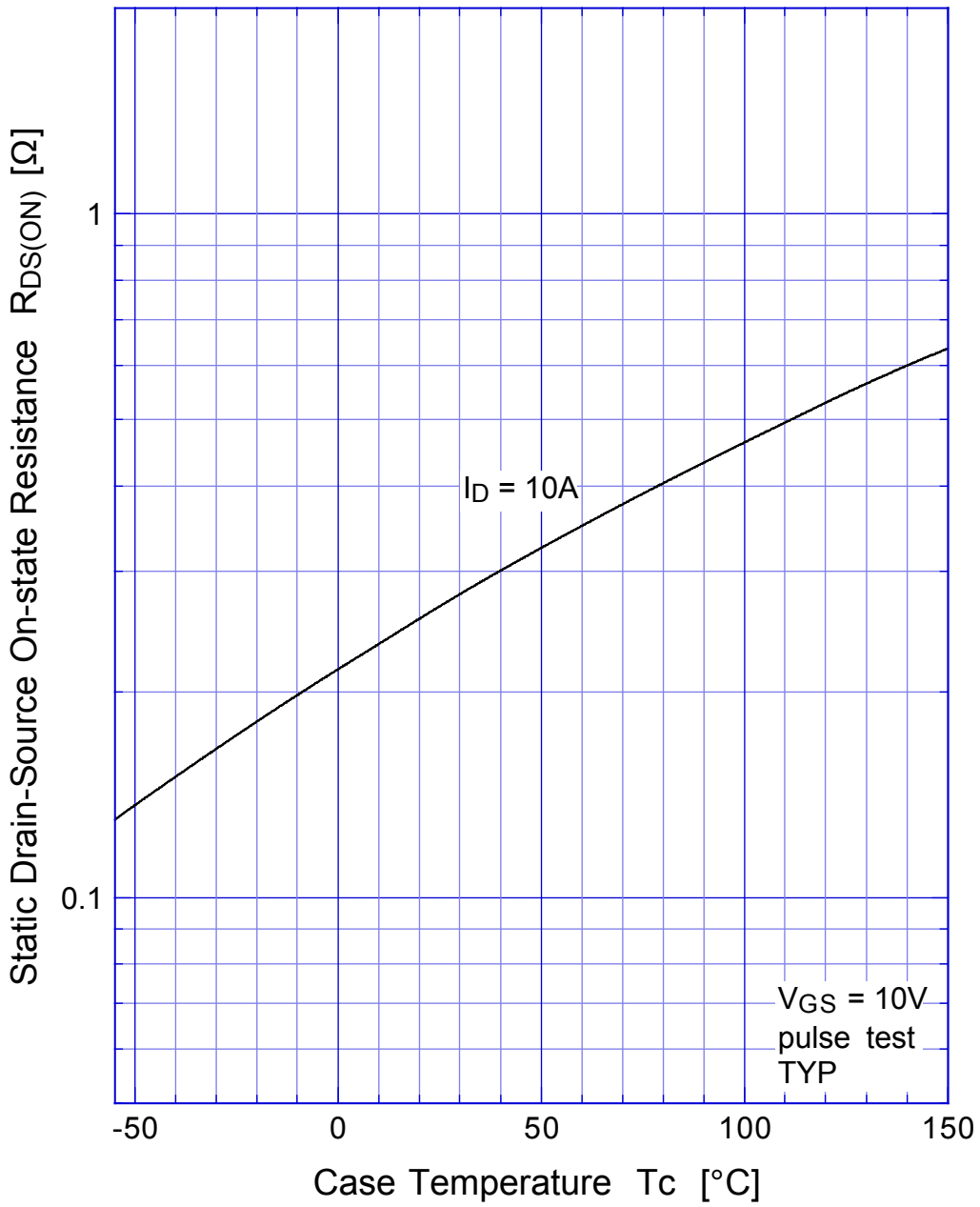
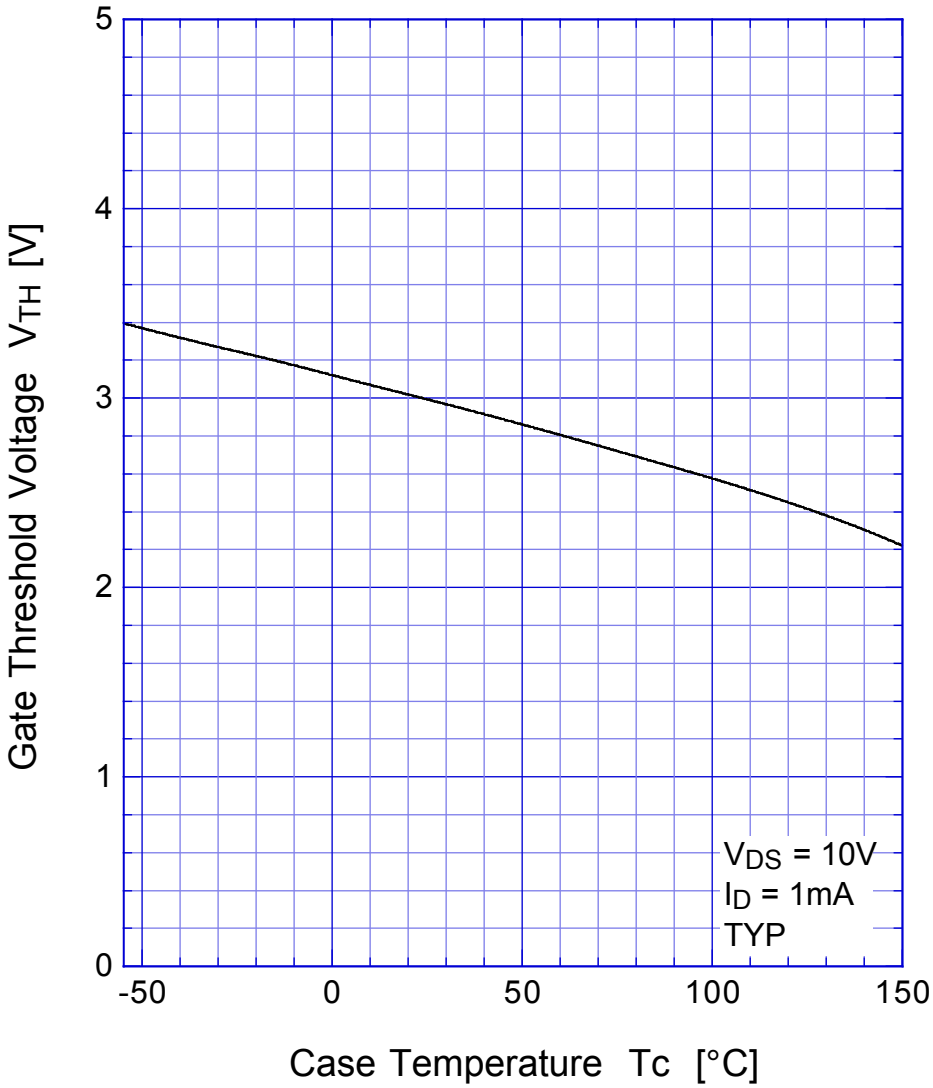

2SK2197
Transfer Characteristics
Tc = −55°C
25°C
100°C
150°C
VDS = 25V
pulse test
TYP
Drain Current ID [A]
Gate-Source Voltage VGS [V]
0
5
10
15
20
25
30
35
40

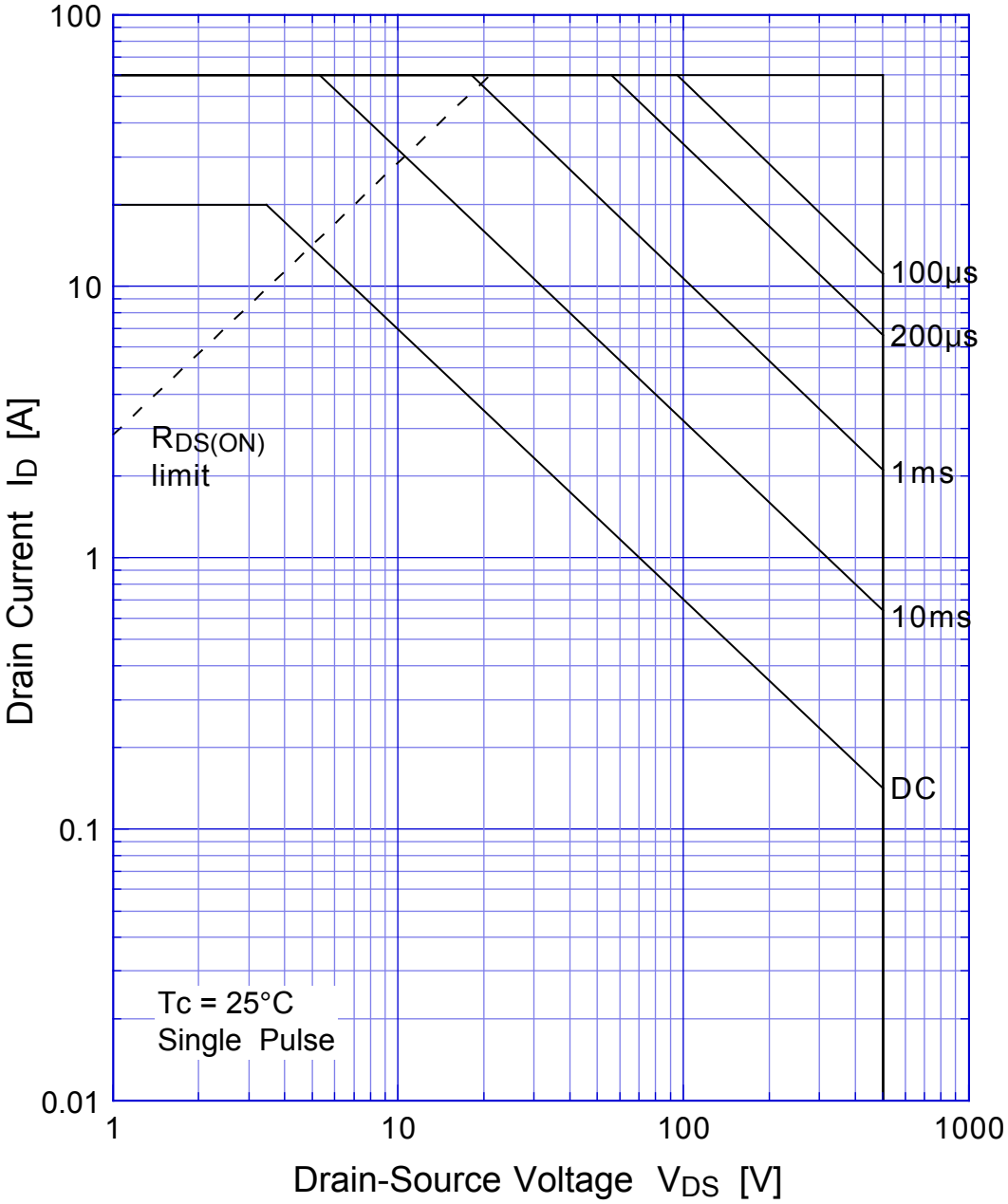
2SK2197 Static Drain-Source On-state Resistance



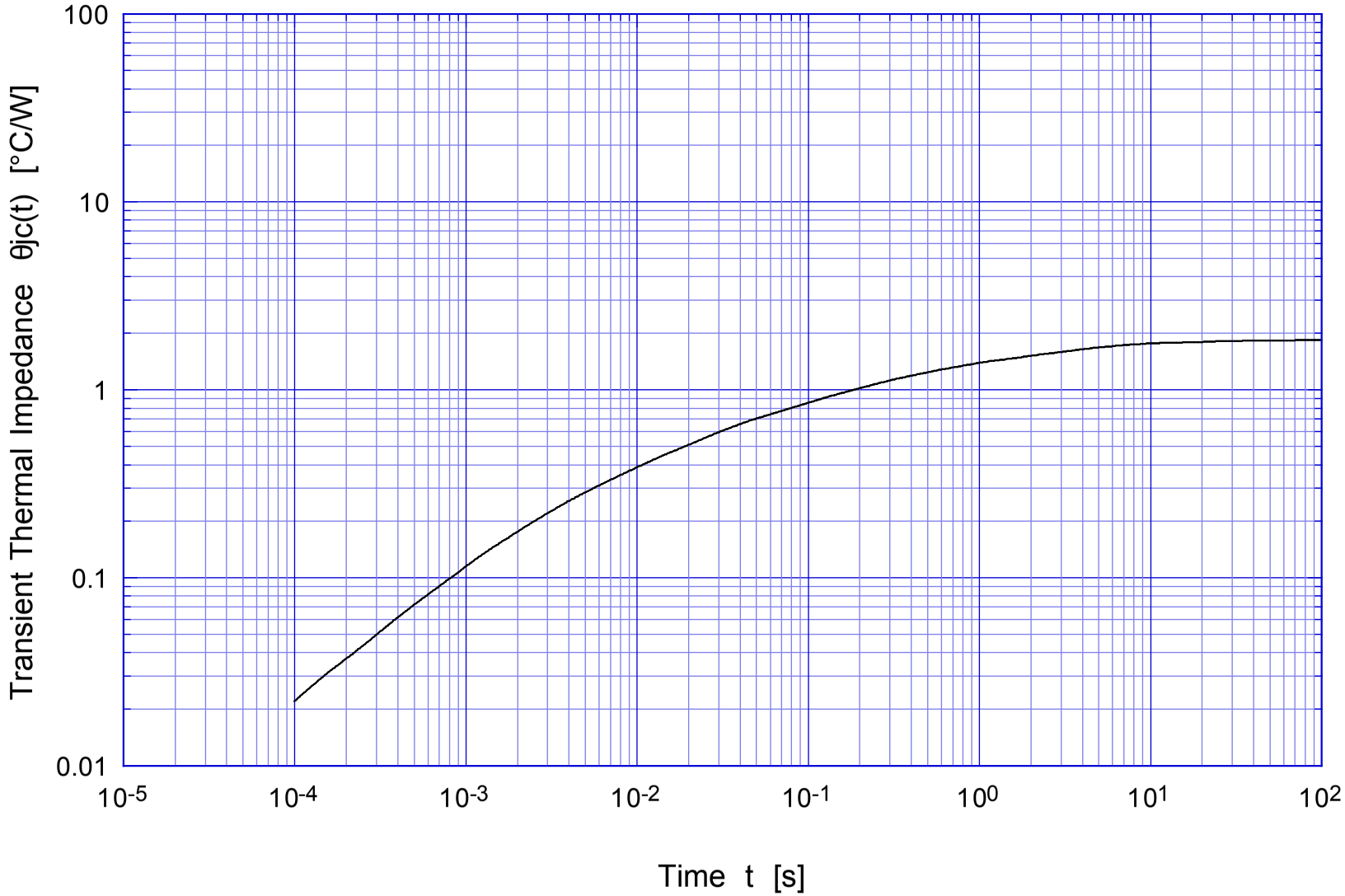
2SK2197 Gate Threshold Voltage



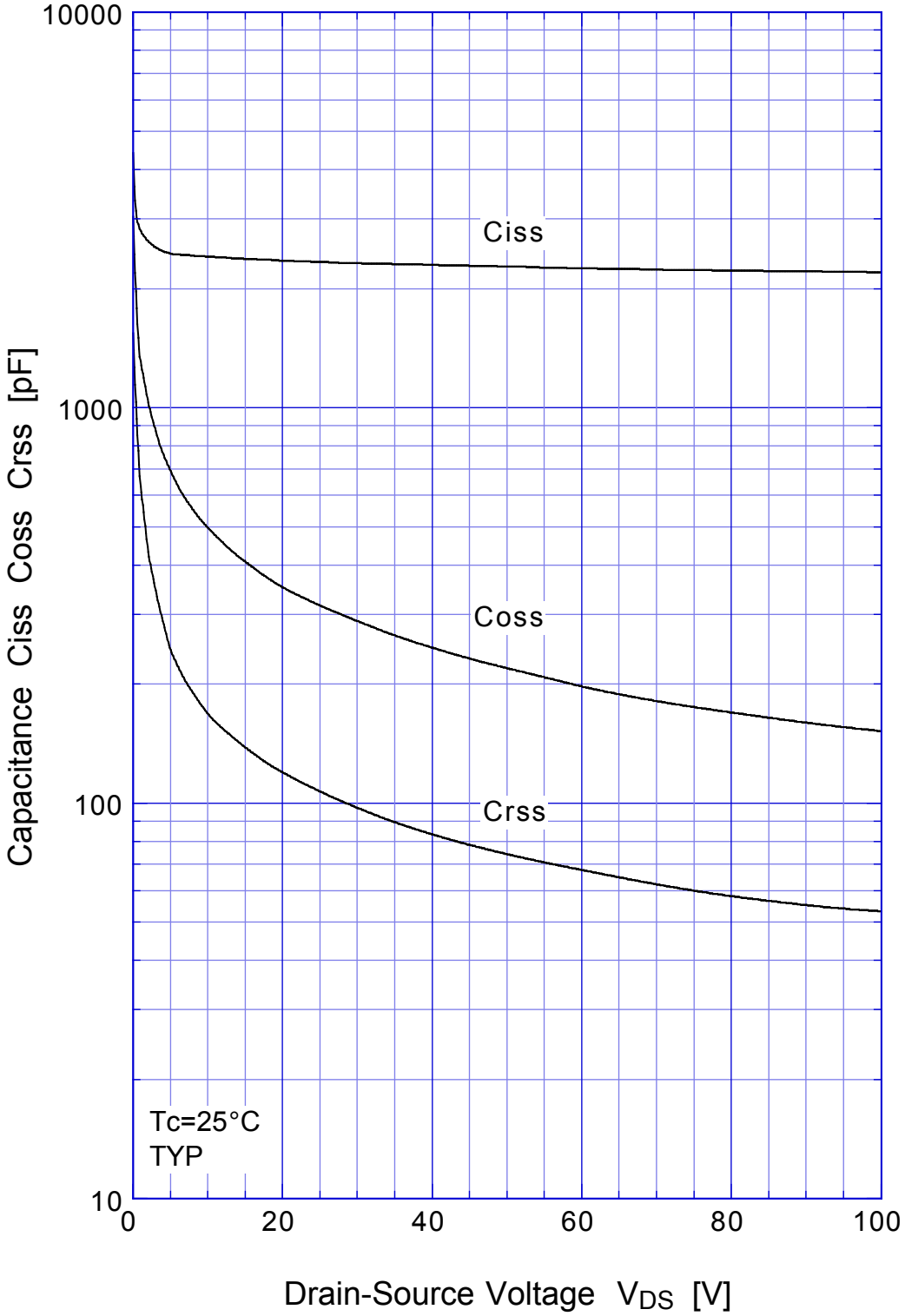
2SK2197 Safe Operating Area

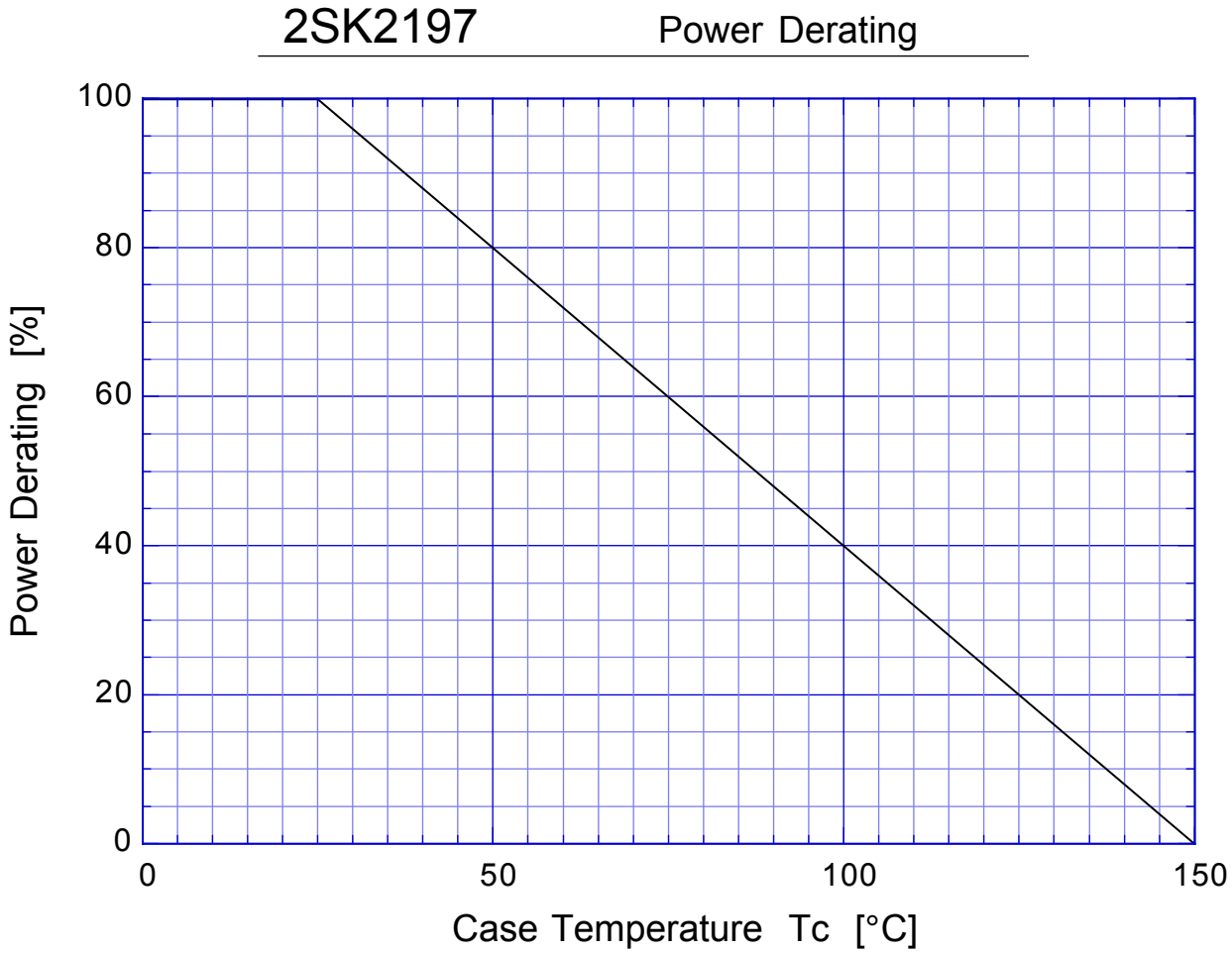
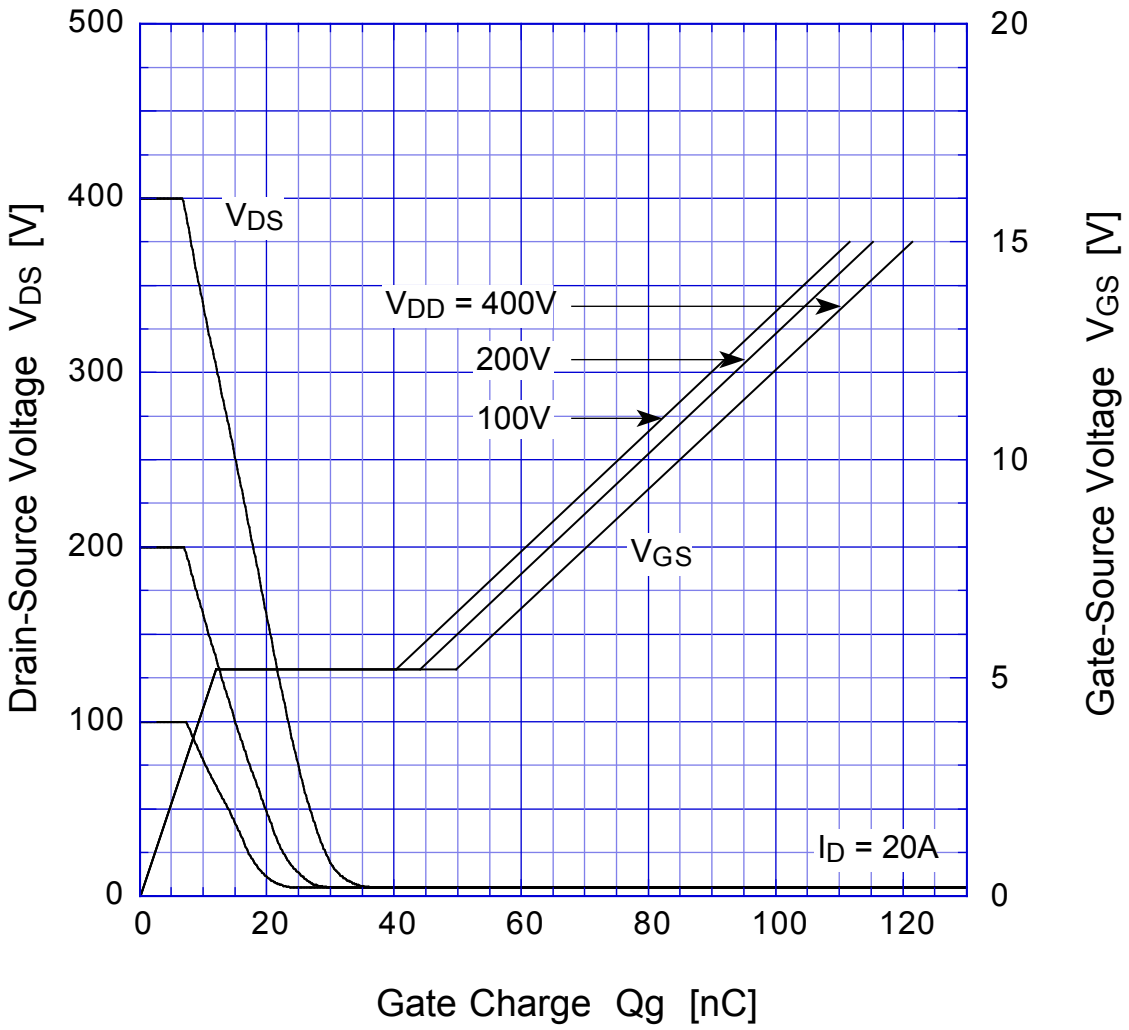


2SK2197 Transient Thermal Impedance



2SK2197 Capacitance




2SK2197
Power Derating
100
80
60
40
20
0
Power Derating [%]
0
50
100
150
Case Temperature Tc [°C]

2SK2197 Gate Charge Characteristics